

ICT UTILIZATION SHEET

Target Section : II ECE
Academic Year : 2024-25
Course Name : Analog Circuits
Source : NPTTEL

Date : 10/8/24
Sem : II-I

Speaker Name & Dr. S. Parasuraman
Affiliation : IIT Madras

Time & Duration : 50 min.

Faculty Name : A. Aravind

COVERED TOPICS

1. MOSFET Characteristics.
2. Construction of MOSFET

VENUE AND UTILIZATION TOOLS

1. S-09 (II ECE) class room.
2. projector.
3. laptop.

Remarks (if any) :

A. Aravind
Signature of the Faculty

[Signature]
ICT Coordinator

[Signature]
HOD

Subject: Analog circuits

Academic Year: 2024-25

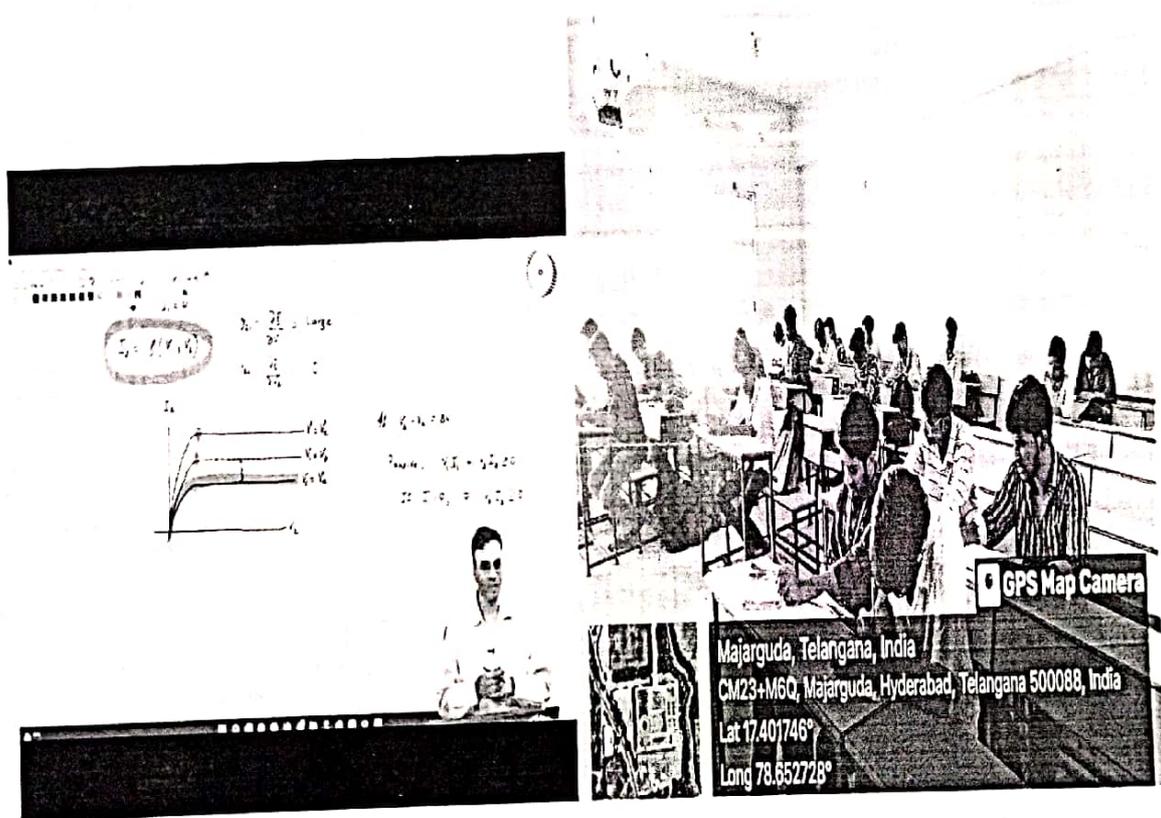
Year/Sem: II -I

Branch: ECE

Name of the Topic: MOSFET Characteristics

Link:

https://www.youtube.com/watch?v=_ueBgOV0gSM&list=PLyqSpQzTE6M9YEdrct_JIT8WWmGMEXcPA&index=9



With this NPTEL video student were able to understand the concepts of MOSFET and solve the problems on MOSFET characteristics